## Wei Bo Associates HK Limited

## MSW2T-2050-194/MSW2T-2051-194

## SP2T Surface Mount High Power PIN Diode Switch

## Features:

- Wide Operating Frequency Band: 50 MHz to 4 GHz , in two bands
- Surface Mount SP2T Switch $-5 \mathrm{~mm} \times 8 \mathrm{~mm} \times 2.5 \mathrm{~mm}$
- Industry Leading Average Power Handling - 160W CW
- High Voltage rating greater than 500V support Higher RF Peak Power - >630W
- Low Insertion Loss (<0.25 dB) and High IP3 (>65 dBm)
- Operates from Positive Only Voltages: +5 V and +28 V to +125 V
- High Linearity
- RoHS Compliant


## Description:

The MSW2T-205X-194 series SP2T surface mount High Power PIN Diode switches are available in two operating frequency bands: MSW2T-2050-194 operates from 50 MHz to 1 GHz and MSW2T-2051-194 operates from 400 MHz to 4 GHz . The MSW2T-205X-194 series of high power switches leverage high reliability hybrid manufacturing processes which yield proven superior performance to both MMIC and Glass Carrier based technologies. The hybrid design approach permits precise PIN Diode selection to optimize RF performance while maintaining competitive cost targets. The small form factor ( $8 \mathrm{~mm} \times 5 \mathrm{~mm} \times 2.5 \mathrm{~mm}$ ) offers world class power handling, low insertion loss, and superior intermodulation performance exceeding all competitive technologies.

The MSW205X-194 family of asymmetrical switches are tailored to minimize Transmit to Antenna loss while maximizing Transmit to Receive isolation and to enable maximum flexibility as the designer can assign either port as Transmit Port and the other the Receive Port. The extremely low thermal resistance of the hybrid assembly permits reliably handling up to 50 dBm CW power and up to 58 dBm peak RF incident power while operating at the $\mathrm{T}_{(\mathrm{amb}) \operatorname{MAX}}=+85^{\circ} \mathrm{C}$.

## Typical Applications:

- Radar T/R Modules
- High Power Transmit/Receive Switching
- Switch Bank Filters
- Mil-Com Radios

The MSW2T-205X-194 series of High Power SP2T switches are intended for use in high power, high reliability, mission critical applications across the HF to S Band frequency ranges. The manufacturing process has been proven through decades of extensive use in high reliability applications.

## ESD and Moisture Sensitivity Level Rating:

The MSW2T-205X-194 family of SP2T switches are fully RoHS compliant. The MSW2T-205X-194 carries an ESD ratings of Class 1C, Human Body Model (HBM) and a moisture sensitivity rating of MSL 1.

MSW2T-205X-194 Schematic


## Control Truth Table for MSW2T-205X-194

$+\mathrm{V}_{\mathrm{cc} 1}=5 \mathrm{~V}$ and $+\mathrm{V}_{\mathrm{cc} 2}=28 \mathrm{~V}$ ( unless otherwise noted)

|  | State 1 | State 2 |
| :---: | :---: | :---: |
| Condition | Tx-Ant: Low Insertion Loss Tx-Rx: Isolation | Ant-Rx: Low Insertion Loss Rx-Tx: Isolation |
| ANT | +5V @ +100mA | +5V @ +100mA |
| TX | 0V @ +100mA | +28V @ 0 mA |
| RX | +28V @ 25mA | 0V @ +100mA |
| B1 | 0V @ +25mA | +28V @ 0mA |

Notes:

1) $28 \mathrm{~V} \leq \mathrm{V}_{\text {HIGH }} \leq 125 \mathrm{~V}$
2) PIN diode min reverse DC voltage $\left(\mathrm{V}_{\text {HIGH }}\right)$ to maintain high resistance state in the OFF PIN diode is determined by RF frequency. Incident power, duty cycle, characteristic impedance and VSWR as well as by characteristics of the diode. The recommended min reverse bias voltage ( $\mathrm{V}_{\text {HIGH }}$ ) values are provided in the Min Reverse Bias Voltage Table of this data sheet.

Control Conditions Table

|  | State 1 | State 2 |
| :---: | :---: | :---: |
| Condition | Tx-Ant: Low Insertion Loss <br> Tx-Rx: Isolation | Ant-Rx: Low Insertion Loss <br> Rx-Tx: Isolation |
| ANT | $+5 \mathrm{~V} \mathrm{@} \mathrm{+100mA}$ | $+5 \mathrm{~V} @+100 \mathrm{~mA}$ |
| TX | $0 \mathrm{~V} \mathrm{@} \mathrm{+100mA}$ | $+28 \mathrm{~V} @ 0 \mathrm{~mA}$ |
| RX | $+28 \mathrm{~V} @ 25 \mathrm{~mA}$ | $0 \mathrm{~V} @+100 \mathrm{~mA}$ |
| DC | $0 \mathrm{~V} @+25 \mathrm{~mA}$ | $+28 \mathrm{~V} @ 0 \mathrm{~mA}$ |

MSW2T-2050-194 Electrical Specifications $@ Z o=50 \Omega ; \mathrm{Ta}=+25^{\circ} \mathrm{C}$

| Parameter | Symbol | Test Condition | Min Value | Typ Value | Max Value | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Frequency | F |  | 50 |  | 1,000 | MHz |
| Tx-Ant Insertion Loss | IL (Tx) | Condition 1 |  | 0.15 | 0.25 | dB |
| Ant-Rx Insertion Loss | IL (Rx) | Condition 2 |  | 0.25 | 0.35 | dB |
| Tx-Ant Return Loss | RL (Tx) | Condition 1 | 18 | 20 |  |  |
| Ant-Rx Return Loss | $R \mathrm{~L}(\mathrm{Rx})$ | Condition 2 | 20 | 22 |  | dB |
| $T x-R x$ Isolation | ISO (Tx) | Condition 1 | 47 | 50 |  |  |
| $R x-T x$ Isolation | ISO (Rx) | Condition 2 | 23 | 26 |  | dB |
| Tx CW Incident Power (Note 2) | Pinc(CW) | Condition 1, Source \& Load VSWR $=1.5: 1$ |  |  | 52 |  |
| Rx CW Incident Power (Note 2) | Pinc(CW) | Condition 2, <br> Source \& Load VSWR $=1.5: 1$ |  |  | 43 | dBm |
| Peak Incident Power (Note 2) | Pinc(Pk) | $\begin{aligned} & \text { Source \& Load VSWR }=1.5: 1 \\ & \text { Pulse width }=10 \text { us, Duty Cycle }=1 \% \end{aligned}$ |  |  | 58 | dB |
| Switching Time | $t_{\text {sw }}$ | Condition 1, $10 \%$ to $90 \%$ RF Voltage, TTL rep rate $=100 \mathrm{kHz}$ |  | 1 | 1.5 | usec |
| Input $3^{\text {rd }}$ Order Intercept Point | IIP3 | $\begin{gathered} \mathrm{F}_{1}=500 \mathrm{MHz}, \mathrm{~F}_{2}=510 \mathrm{MHz}, \\ \mathrm{P}_{1}=\mathrm{P}_{2}=40 \mathrm{dBm} \end{gathered}$ | 60 | 65 |  | dBm |

## MSW2T-2050-194 Electrical Specifications @ Zo $=50 \Omega ; \mathrm{Ta}=+25^{\circ} \mathrm{C}$

| Parameter | Symbol | Test Condition | Min Value | Typ Value | Max Value | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Frequency | F |  | 400 |  | 4,000 | MHz |
| Tx-Ant Insertion Loss | IL (Tx) | Condition 1 |  | 0.3 | 0.4 | dB |
| Ant - Rx Insertion Loss | IL (Rx) | Condition 2 |  | 0.8 | 0.9 | dB |
| Tx-Ant Return Loss | RL (Tx) | Condition 1 | 15 | 17 |  |  |
| Ant-Rx Return Loss | RL (Rx) | Condition 2 | 15 | 17 |  | dB |
| $T x-R x$ <br> Isolation | ISO (Tx) | Condition 1 | 32 | 34 |  |  |
| $R x-T x$ Isolation | ISO (Rx) | Condition 2 | 11 | 13 |  | dB |
| Tx CW Incident Power (Note 2) | Pinc(CW) | Condition 1, Source \& Load VSWR $=1.5: 1$ |  |  | 52 |  |
| Rx CW Incident Power (Note 2) | Pinc(CW) | Condition 2, Source \& Load VSWR $=1.5: 1$ |  |  | 43 | dBm |
| Peak Incident Power (Note 2) | Pinc(Pk) | Source \& Load VSWR = 1.5:1 <br> Pulse width = 10 us, Duty Cycle = 1\% |  |  | 58 | dB |
| Switching Time | $t_{\text {sw }}$ | Condition 1, 10\% to $90 \%$ RF Voltage, TTL rep rate $=100 \mathrm{kHz}$ |  | 1 | 1.5 | usec |
| Input $3^{\text {rd }}$ Order Intercept Point | IIP3 | $\begin{gathered} \mathrm{F}_{1}=500 \mathrm{MHz}, \mathrm{~F}_{2}=510 \mathrm{MHz}, \\ \mathrm{P}_{1}=\mathrm{P}_{2}=40 \mathrm{dBm} \\ \hline \end{gathered}$ | 60 | 65 |  | dBm |

Notes:

1) Switching speed from $50 \%$ TTL control signal to $10 \% / 90 \%$ RF Voltage is a function of the PIN diode driver performance in conjunction with the PIN diode characteristics. An RC "current spiking network" may be used on the driver output to provide a transient current to rapidly removed stored charge from the I region of the PIN diode. Typical component values are: R=50 to $220 \Omega$ and $C=470$ to $1,000 \mathrm{pF}$.
2) The PIN diode DC reverse voltage used to maintain a high resistance state during the OFF state is determined by the RF frequency, incident power, and VSWR as well as the characteristics of the PIN diode. The minimum reverse bias voltage values are provided in this data sheet. The input signal level applied to test small signal performance is 0 dBm .

## RF Bias Network Recommended Component Values

| Part Number | Operating <br> Frequency <br> $(M H z)$ | DC Blocking <br> Capacitors | Inductors | RF Bypass <br> Capacitors |
| :---: | :---: | :---: | :---: | :---: |
| MSW2T-2050-194 | $50-1,000$ | $0.1 \mu \mathrm{~F}$ | $4.7 \mu \mathrm{H}$ | $0.1 \mu \mathrm{~F}$ |
| MSW2T-2051-194 | $400-4,000$ | 27 pF | 82 nH | 270 pF |

## MSW2T-205X-194 Minimum Reverse Bias Voltage Table

|  | Frequency of Operation (MHz) |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Part Number | $20-100$ | $100-200$ | $200-400$ | $400-1,000$ | $1,000-4,000$ | $>4,000$ |
| MSW2T-2050-194 | 125 V | 125 V | 85 V | 55 V | 28 V | N/A |
| MSW2T-2051-194 | N/A | N/A | 125 V | 85 V | 55 V | 28 V |

[^0]MSW2T-205X-194 Absolute Maximum Ratings @ $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ (unless otherwise denoted)

| Parameters | Conditions | Absolute Maximum Value |
| :---: | :---: | :---: |
| Forward Current -Ant, Tx or Rx Port |  | 250 mA |
| Forward Current - DC Port |  | 150 mA |
| Reverse Voltage - Tx or Rx Port |  | 125 V |
| Reverse Voltage - DC Port |  | 125 V |
| Forward Diode Voltage | $\mathrm{I}_{\mathrm{F}}=250 \mathrm{~mA}$ | 1.2 V - |
| Operating Temperature |  | $-55^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Storage Temperature |  | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Junction Temperature |  | $+175^{\circ} \mathrm{C}$ |
| Assembly Temperature |  | $260^{\circ} \mathrm{C}$ for 10 sec |
| CW Incident Power Handling Tx or Antenna Port (Note 1) | Source \& Load VSWR = 1.5:1, TCASE $=85^{\circ} \mathrm{C}$, cold switching | 52 dBm |
| CW Incident Power Handling Rx or Antenna Port (Note 1) | Source \& Load VSWR = 1.5:1, $\mathrm{T}_{\text {CASE }}=85^{\circ} \mathrm{C}$, cold switching | 43 dBm |
| Peak Incident Power Handling Tx or Antenna Port (Note 1) | Source \& Load VSWR $=1.5: 1$, <br> TCASE $=850 \mathrm{C}$, cold switching, <br> Pulse Width $=10$ us, Duty Cycle $=1 \%$ | 58 dBm |
| Total Dissipated RF \& DC Power (Note 1) | TCASE $=850 \mathrm{C}$, cold switching | 8W |

Notes:

1) Backside RF, DC and Thermal Ground area of device must be completely solder attached to RF circuit board vias for proper electrical and thermal circuit grounding.

## MSW2T-2050-194 Small Signal Parametric Performance:

MSW2T-2050-194: TX and Rx Insertion Loss vs Frequency


MSW2T-2050-194: Tx and Rx Return Loss vs Frequency


MSW2T-2050-194: Tx and Rx Isolation vs Frequency


MSW2T-2051-194: Small Signal Parametric Performance:
MSW2T-2051-194: Tx-Ant and Ant-Rx Insertion Loss vs Frequency


MSW2T-2051-194: Tx-Ant and Ant-Rx Return Loss vs Frequency


MSW2T-2051-194: Tx-Ant and Ant-Rx Isolation vs Frequency


## Assembly Instructions

The MSW2T-205X-194 family of High Power Switches are available in either tube or Tape \& Reel format. The MSW2T-205X-194 may be attached to the printed circuit card using solder reflow procedures using either RoHS or Sn63/ Pb37 type solders per the Table and Temperature Profile Graph shown below:

| Profile Parameter | Sn-Pb Assembly Technique | RoHS Assembly Technique |
| :---: | :---: | :---: |
| Average ramp-up rate ( $T_{L}$ to $\mathrm{T}_{\mathrm{p}}$ ) | $3^{\circ} \mathrm{C} / \mathrm{sec}$ (max) | $3^{\circ} \mathrm{C} / \mathrm{sec}$ (max) |
| $\begin{aligned} & \text { Preheat } \\ & \text { Temp Min }\left(T_{\text {smin }}\right) \\ & \text { Temp Max }\left(T_{\text {smax }}\right) \\ & \text { Time }(\min \text { to } \max )\left(\mathrm{t}_{\mathrm{s}}\right) \end{aligned}$ | $\begin{gathered} 100^{\circ} \mathrm{C} \\ 150^{\circ} \mathrm{C} \\ 60-120 \mathrm{sec} \end{gathered}$ | $\begin{gathered} 100^{\circ} \mathrm{C} \\ 200^{\circ} \mathrm{C} \\ 60-180 \mathrm{sec} \end{gathered}$ |
| $\begin{aligned} & \hline \mathrm{T}_{\text {smax }} \text { to } \mathrm{T}_{\mathrm{L}} \\ & \text { Ramp up Rate } \\ & \hline \end{aligned}$ |  | $3^{\circ} \mathrm{C} / \mathrm{sec}(\max )$ |
| Peak Temp ( $\mathrm{T}_{\mathrm{p}}$ ) | $225^{\circ} \mathrm{C}+0^{\circ} \mathrm{C} /-5^{\circ} \mathrm{C}$ | $260^{\circ} \mathrm{C}+0^{\circ} \mathrm{C} /-5^{\circ} \mathrm{C}$ |
| Time within $5^{\circ} \mathrm{C}$ of Actual Peak Temp ( $\mathrm{T}_{\mathrm{p}}$ ) | 10 to 30 sec | 20 to 40 sec |
| ```Time Maintained Above: Temp (TL) Time (t }\mp@subsup{\textrm{L}}{\textrm{L}}{``` | $\begin{gathered} 183^{\circ} \mathrm{C} \\ 60 \text { to } 150 \mathrm{sec} \end{gathered}$ | $\begin{gathered} 217^{\circ} \mathrm{C} \\ 60 \text { to } 150 \mathrm{sec} \end{gathered}$ |
| Ramp Down Rate | $6^{\circ} \mathrm{C} / \mathrm{sec}$ (max) | $6^{\circ} \mathrm{C} / \mathrm{sec}(\mathrm{max})$ |
| Time $25^{\circ} \mathrm{C}$ to $\mathrm{T}_{\mathrm{P}}$ | 6 minutes (max) | 8 minutes (max) |

## Solder Re-Flow Time-Temperature Profile



MSW2T-205X-194 SP2T Package Outline Drawing


Note: Metalized area on backside is the RF, DC and Thermal ground. In user's end application this surface temperature must be managed to meet the power handling requirements.

## Thermal Design Considerations:

The design of the MSW2T-205X-194 family of High Power Switches permits the maximum efficiency in thermal management of the PIN Diodes while maintaining extremely high reliability. Optimum switch performance and reliability of the switch can be achieved by the maintaining the base ground surface temperature of less than $85^{\circ} \mathrm{C}$.

## Recommended RF Circuit Solder Footprint for the MSW2T-205X-194



Notes:

1) All dimensions in inches.
2) Recommended RF Circuit Rogers: R04350B, 10 mils Thick.

Part Number Ordering Details:

| Part Number | Packaging |
| :--- | :--- |
| MSW2T-2050-194 | Tube |
| MSW2T-2050-194TR | Tape \& Reel (250 pcs) |
| MSW2T-2051-194 | Tube |
| MSW2T-2051-194TR | Tape \& Reel (250 pcs) |


[^0]:    Note: N/A denotes an operating frequency outside the normal switch operating frequency range.

